COMCHIP
SMD DIODE SPECIALIST

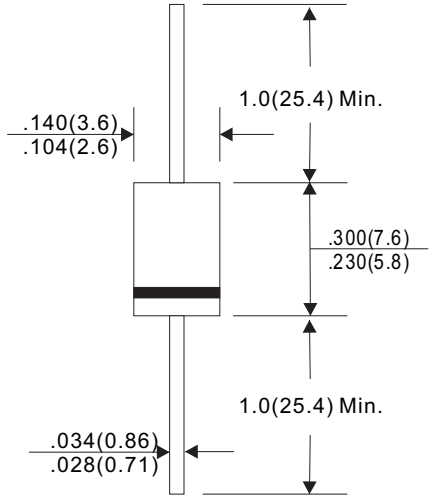
SB220E-G thru SB2100E-G "-G" : RoHS Device

Voltage Range: 20 to 100 V
Current: 2.0 A

FEATURES

- Low drop down voltage
- 2.0A operation at T_A=75°C with no thermal runaway
- For use in low voltage, high frequency invertors free wheeling and polarity protection
- Silicon epitaxial planar chips
- Electrostatic discharge (ESD) test under IEC61000-4-2: standard: >15KV (air) & 8KV (contact)
- Lead-free part, meet RoHS requirements

DO-15



Unit :inch(mm)

MECHANICAL DATA

- Case: Molded plastic body DO-15
- Epoxy: UL94-V0 rated flame retardant
- Terminals: Solderable per MIL-STD-750 Method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.015 ounces, 0.4 grams

MAXIMUM RATING AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified

	Symbols	220E	240E	245E	250E	260E	280E	2100E	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	20	40	45	50	60	80	100	Volts
Maximum RMS Voltage	V_{RMS}	14	28	30	35	42	56	70	Volts
Maximum DC Blocking Voltage	V_{DC}	20	40	45	50	60	80	100	Volts
Maximum Average Forward Rectified Current 0.375" (9.5mm) lead length at T_A=75°C, See Figure 1	I_{AV}	2.0							Amps
Peak Forward Surge Current 8.3mS single half sine-wave superimposed on rated load (JEDEC Method) T_L=110°C	I_{FSM}	50							Amps
Maximum Forward Voltage at 2.0A (Note 1)	V_F	0.50			0.70		0.85		Volts
Maximum DC Reverse Current T_A= 25°C	I_R	0.5							mA
at Rated DC Blocking Voltage T_A=100°C		20					10		
Typical Junction Capacitance (Note 2)	C_J	170							pF
Typical Thermal Resistance (Note 3)	$R_{\theta JA}$ $R_{\theta JL}$	50.0 25.0							°C/W
Operating Junction Temperature Range	T_J	-65 ~ +125					-65 ~ +150		°C
Storage Temperature Range	T_{STG}	-65 ~ +150							°C

Note 1. Pulse test: 300μS pulse width, 1% duty cycle
2. Measured at 1.0MHz and applied reverse voltage of 4.0 Volts
3. Thermal resistance from junction to ambient and from junction to lead P.C.B. mounted 0.375" (9.5mm) lead length

RATINGS AND CHARACTERISTIC CURVES SB220E-G thru SB2100E-G

Fig.1 - Forward Current Derating Curve

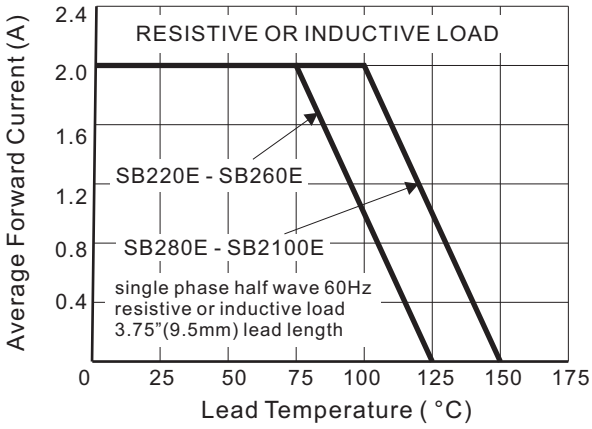


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

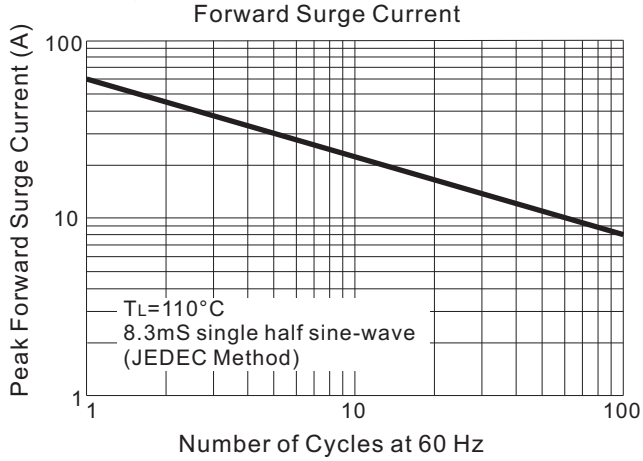


Fig. 3 - Typical Instantaneour Forward Characteristics

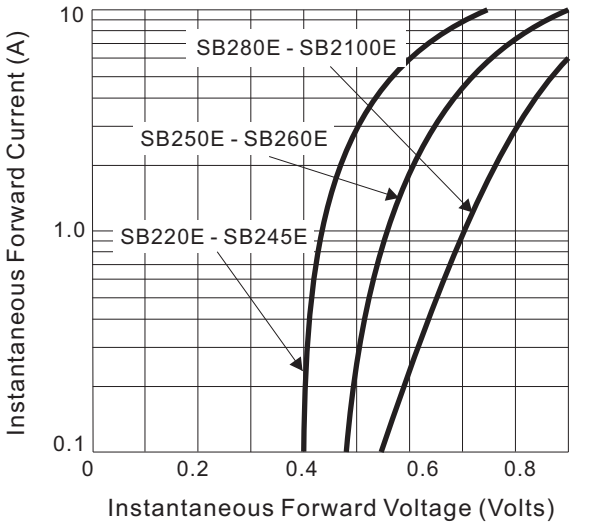


Fig. 4A - Typical Reverse Characteristics

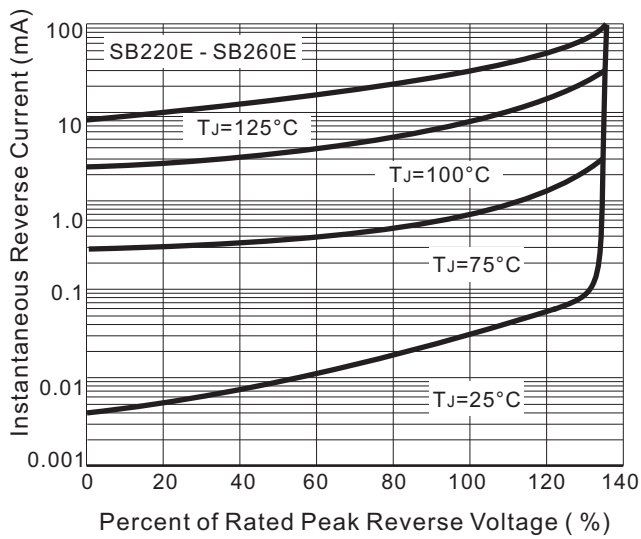


Fig. 5 - Typical Junction Capacitance

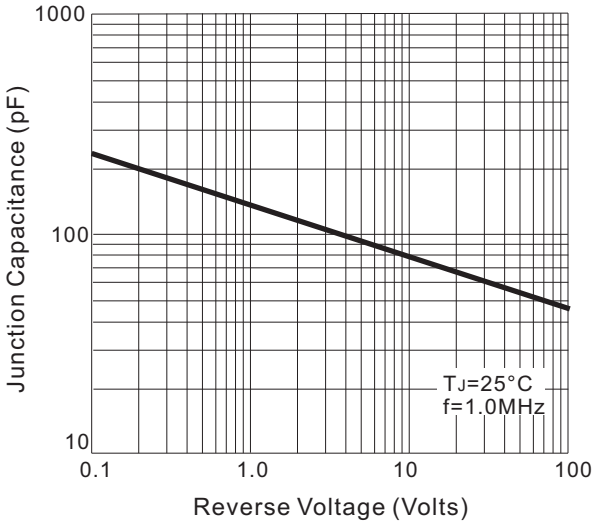


Fig. 4B - Typeical Reverse Characteristic